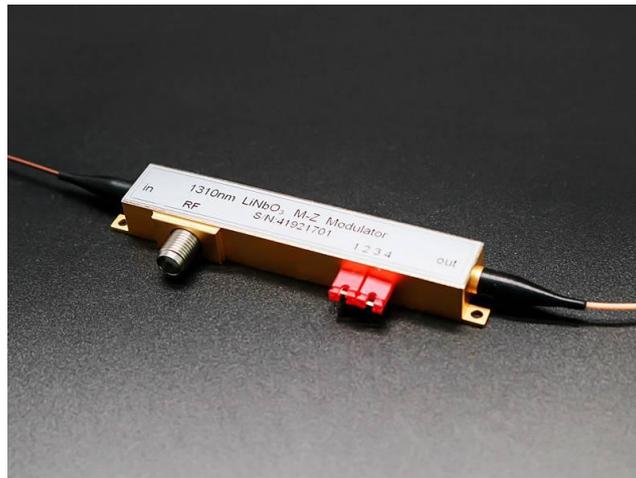


1310nm LiNbO3 2.5Gb/s Intensity Modulator



● Product Description

Idealphotonics' lithium niobate (LiNbO3) intensity modulator is made of Mach-Zehnder type optical waveguide by titanium diffusion or proton exchange process. The input and output optical fibers are precisely obliquely coupled to the waveguide, and the electro-optical effect of lithium niobate material is used to achieve intensity modulation of the optical signal.

● Product features

X-cut Y-transmitted LiNbO3 、 Titanium diffused or proton exchange waveguide、 Low drive voltage、 Independent bias electrode Zero chirp、

Precise oblique coupling between fiber and chip greatly reduces Back reflection、 Excellent long-term stability

● Part Number

MP-EOM-IM-1310-3G-FA

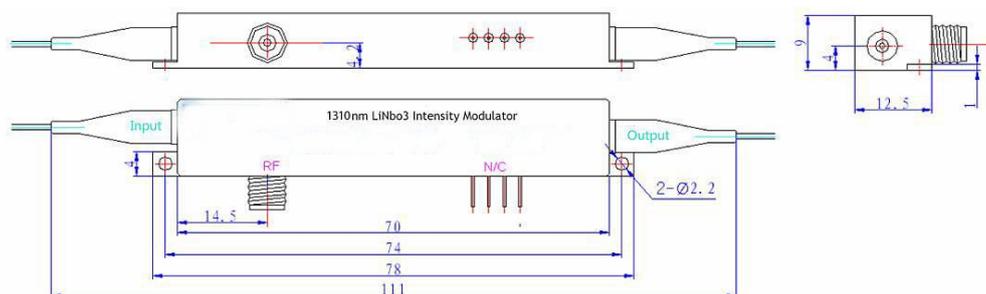
● Application area

Pulse generation, pulse shaping, pulse picking、 Carrier suppression、 Fiber optic sensing system、 Pulse application、 Analog transmission、 Laser radar

● Core parameters

| Wavelength | Bandwidth | Connector |
|------------|-----------|-----------|
| 1310nm | 3GHz | FC/APC |

● Dimension Drawing



● General Parameters

Parameters

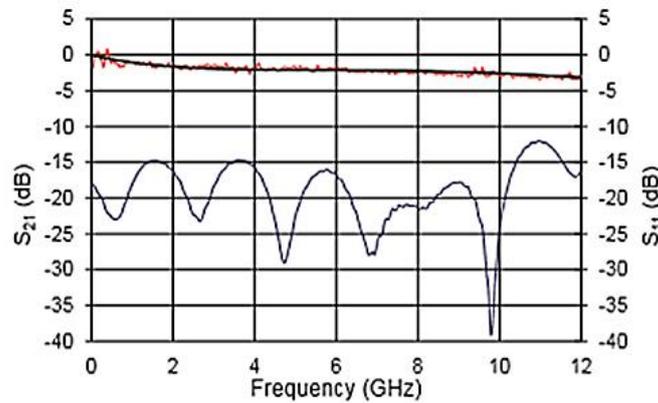
| Parameter | Unit | Min. | Typical | Max. |
|--|------|--|---------|------|
| Half-wave voltage DC electrode | V | | 6.5 | 7.0 |
| Electro-optical bandwidth S21@-3dB | GHz | 3 | | |
| RF half-wave voltage @DC | V | | 3.5 | 4.0 |
| Bias half-wave voltage | V | | | 5.0 |
| Jitter | dB | | 0.5 | 1 |
| Electrical return loss S11@-20GHz | dB | | -12 | -10 |
| RF connector input resistance | Ω | 40 | | |
| Input impedance DC connector | Ω | >1M | | |
| Crystal: Lithium Niobate | | X-cut Y-propagation | | |
| Waveguide process | | APE Process | | |
| Insertion loss | dB | | 3.0 | 4.0 |
| Optical return loss | dB | | <-45 | |
| Wavelength-dependent loss (1480-1600nm) | dB | | 0.5 | 1.0 |
| DC extinction ratio | dB | 20 | 22 | |
| Input fiber | | Panda polarization-maintaining fiber 1.5 meters long, 900um | | |
| Output fiber | | SMF-28 single-mode fiber 1.5 meters long, 900um (PMF optional) | | |
| Input RF connector | | SMA | | |
| DC connector | | Pin feed-through diameter: 1.0mm | | |
| Package size | mm | 110 x12.5 x9.0 | | |
| Operating temperature | °C | 0~ +70 | | |
| Storage temperature | °C | -40 ~ +85 | | |



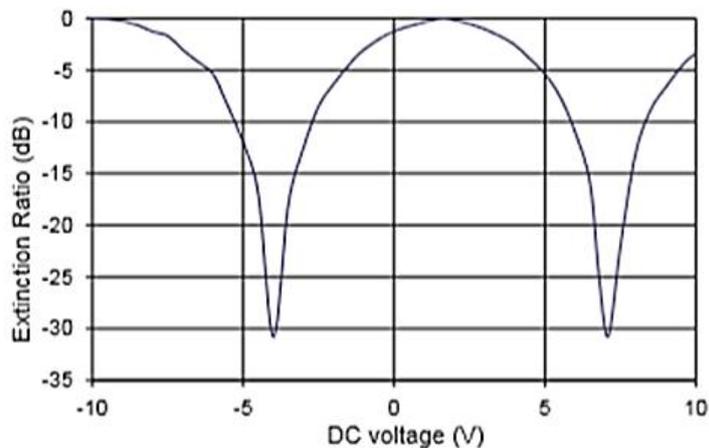
| Parameter | Unit | Min. | Typical | Max. |
|-----------------------------|------|------|-------------------|------|
| DC input maximum voltage | V | | ±20 | |
| Maximum RF input power | dBm | | +28 | |
| Maximum input optical power | mW | | 200 (APE process) | |

* 1064nm, 850nm wavelength can be customized

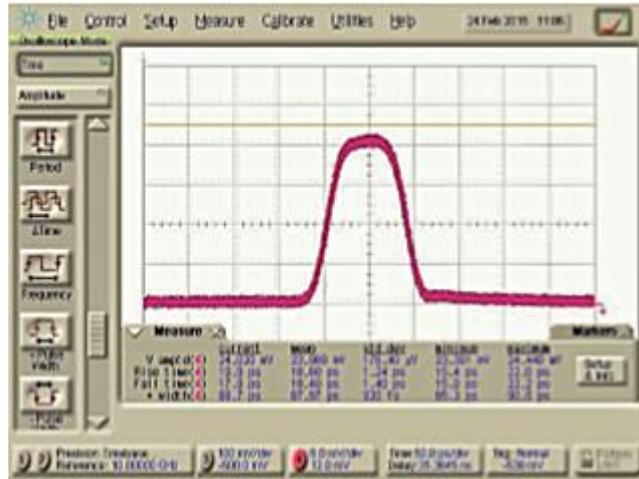
Performance Display



(S21 and S11 curves)



(Pulse extinction ratio)



(100ps square wave pulse generation)

Ordering Information

MP-EOM-IM-W-BW-XX-Y-Z-AB-CD

wavelength:

0850: 850nm

1064: 1064nm

1310: 1310nm

BW: Electro-optical bandwidth

3G represent >03GHz

10G represent >10GHz

Y: input fiber

P represent polarization-maintaining fiber

S represent single mode fiber

Z: output fiber

P represent polarization-maintaining fiber



S represent single mode fiber

AB: input fiber connector

00 represent bare fiber

FA represent FC/APC

FC represent FC/SPC

CD: output fiber connector

00 represent bare fiber

FA represent FC/APC

FC represent FC/SPC